AMENDMENTS TO THE CLAIMS:

Please cancel Claims 1 through 12, 14 and 20 without prejudice or disclaimer of subject matter.

Please amend Claim 13, to read as follows.

1 - 12. (Canceled)

13. (Currently Amended) A piezoelectric actuator comprising a substrate and an epitaxial ferroelectric film provided on said substrate, wherein said epitaxial ferroelectric film satisfies a relation $z/z_0 > 1.003$, where z is the c-axis lattice constant of the epitaxial ferroelectric film and z_0 is the c-axis lattice constant of a material constituting said epitaxial ferroelectric film in a bulk state, and

where x is the a-axis lattice constant of the epitaxial ferroelectric film and x_0 is the a-axis lattice constant of a material constituting said epitaxial ferroelectric film in a bulk state, said epitaxial ferroelectric film has a thickness within a range of 100 nm to 10 μ m, and said epitaxial ferroelectric film includes a lead (Pb) atom and an oxygen (O) atom as constituent atoms.

14. (Canceled)

- 15. (Original) A piezoelectric actuator according to claim 13, further comprising at least a buffer layer between said substrate and said epitaxial ferroelectric film.
- 16. (Original) A piezoelectric actuator according to claim 15, wherein at least one of said substrate and said buffer layer is electroconductive.
- 17. (Previously Presented) A piezoelectric actuator according to claim 13, wherein a crystal orientation degree of a crystal plane of said epitaxial ferroelectric film parallel to a crystal plane of a surface of said substrate, measured by a $2\theta/\theta$ method with an X-ray incident angle θ to the crystal plane of said epitaxial ferroelectric film parallel to the crystal plane of the surface of said substrate, is 90 % or higher.
- 18. (Previously Presented) A piezoelectric actuator according to claim 13, wherein a crystal plane of said epitaxial ferroelectric film parallel to a crystal plane of a surface of said substrate has a crystal orientation degree of 99% or higher.
- 19. (Original) A piezoelectric actuator according to claim 13, wherein said epitaxial ferroelectric film has a perovskite structure.
 - 20. (Canceled)

- 21. (Previously Presented) A piezoelectric actuator according to claim 13, wherein said epitaxial ferroelectric film has a tetragonal crystal structure and a crystal plane of said epitaxial ferroelectric film parallel to a crystal plane of a surface of said substrate is a (001) plane.
- 22. (Previously Presented) A piezoelectric actuator according to claim 13, wherein said epitaxial ferroelectric film has a rhombohedral crystal structure and a crystal plane of said epitaxial ferroelectric film parallel to a crystal plane of a surface of said substrate is a (111) plane.
- 23. (Previously Presented) A piezoelectric actuator according to claim 13, wherein said epitaxial ferroelectric film has a hexagonal crystal structure and a crystal plane of said epitaxial ferroelectric film parallel to a crystal plane of a surface of said substrate is a (0001) plane.
- 24. (Previously Presented) A piezoelectric actuator according to claim 13, wherein said epitaxial ferroelectric film has a rhombic crystal structure and a crystal plane of said epitaxial ferroelectric film parallel to a crystal plane of a surface of said substrate is a (011) plane.
- 25. (Original) A liquid discharge head for discharging a liquid utilizing a piezoelectric actuator according to claim 13.